Ordering number:EN3451

N-Channel Silicon MOSFET

2SK1448

Ultrahigh-Speed Switching Applications

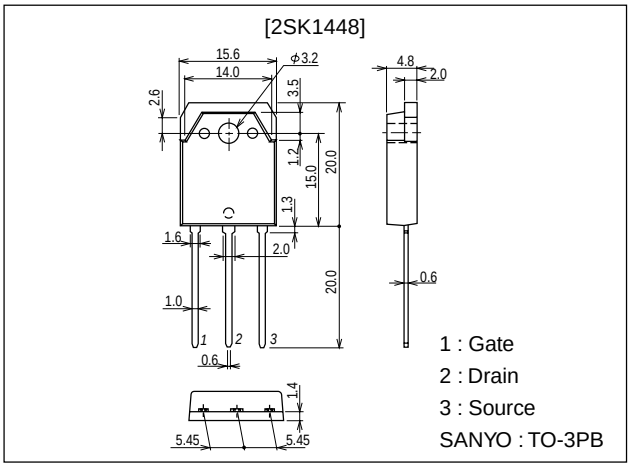
Features

- Low ON-state resistance.
- Ultrahigh-speed switching.

Package Dimensions

unit:mm

2056A



Specifications

Absolute Maximum Ratings at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		450	V
Gate-to-Source Voltage	V_{GSS}		±30	V
Drain Current (DC)	I_D		8	A
Drain Current (Pulse)	I_{DP}	PW≤10μs, duty cycle≤1%	32	A
Allowable Power Dissipation	P_D	Tc=25°C	100	W
			2.5	W
Channel Temperature	Tch		150	˚C
Storage Temperature	Tstg		–55 to +150	˚C

Electrical Characteristics at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	I_D=1mA, V_{GS}=0	450			V
Zero-Gate Voltage Drain Current	I_{DSS}	V_{DS}=450V, V_{GS}=0			1.0	mA
Gate-to-Source Leakage Current	I_{GSS}	V_{GS}=±30V, V_{DS}=0			±100	nA
Cutoff Voltage	$V_{GS(off)}$	V_{DS}=10V, I_D=1mA	2.0		3.0	V
Forward Transfer Admittance	| yfs |	V_{DS}=10V, I_D=4A	3.0	6.0		S
Static Drain-to-Source ON-State Resistance	$R_{DS(on)}$	I_D=4A, V_{GS}=10V		0.6	0.8	Ω

(Note) Be careful in handling the 2SK1448 because it has no protection diode between gate and source.

Continued on next page.

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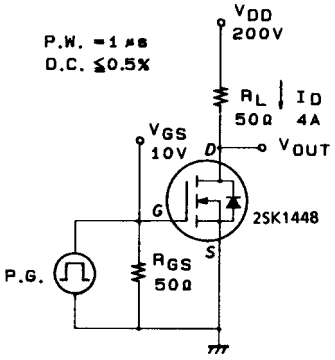
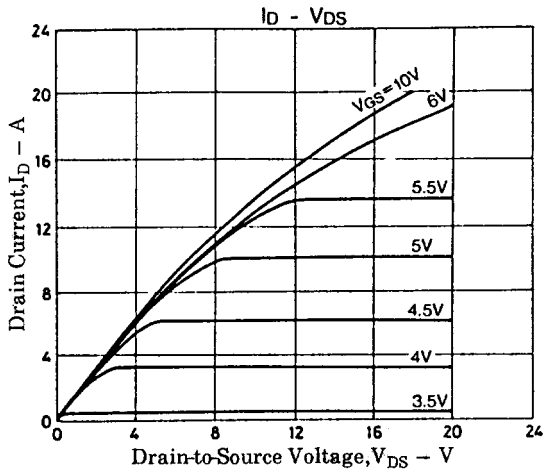
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

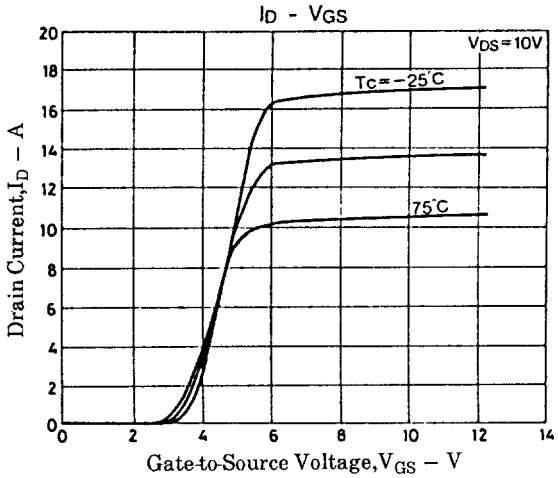
Continued from preceding page.

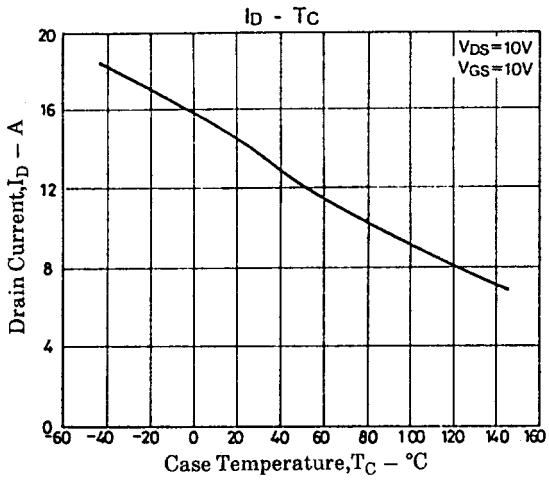
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	V_{DS}=20V, f=1MHz		1200		pF
Output Capacitance	Coss	V_{DS}=20V, f=1MHz		180		pF
Reverse Transfer Capacitance	Crss	V_{DS}=20V, f=1MHz		70		pF
Turn-ON Delay Time	$t_{d(on)}$	I_D=4A, V_{GS}=10V, V_{DD}=200V, R_{GS}=50Ω		20		ns
Rise Time	t_r	I_D=4A, V_{GS}=10V, V_{DD}=200V, R_{GS}=50Ω		40		ns
Turn-OFF Delay Time	$t_{d(off)}$	I_D=4A, V_{GS}=10V, V_{DD}=200V, R_{GS}=50Ω		160		ns
Fall Time	t_f	I_D=4A, V_{GS}=10V, V_{DD}=200V, R_{GS}=50Ω		60		ns
Diode Forward Voltage	V_{SD}	I_S=8A, V_{GS}=0			1.8	V

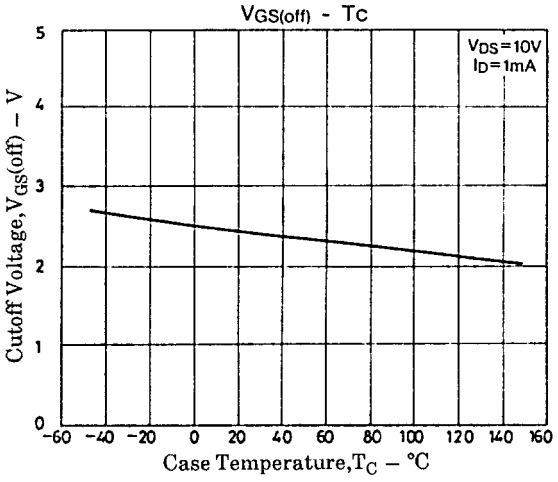
Switching Time Test Circuit

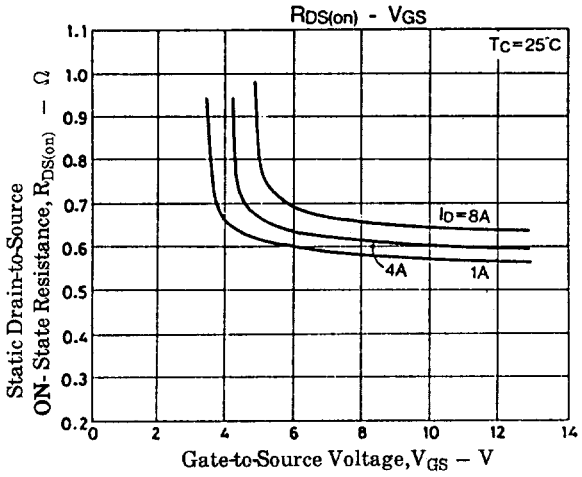


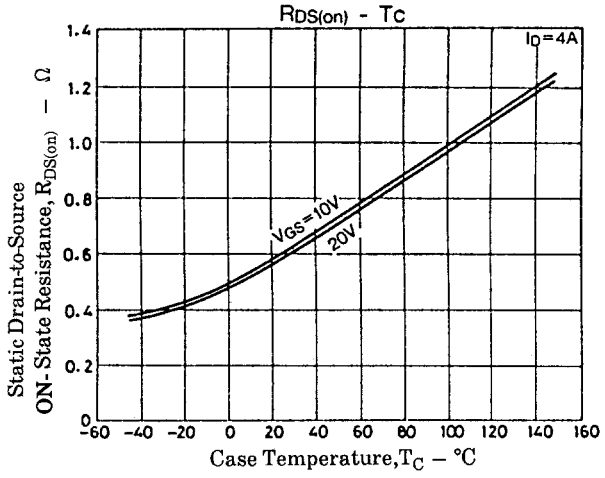


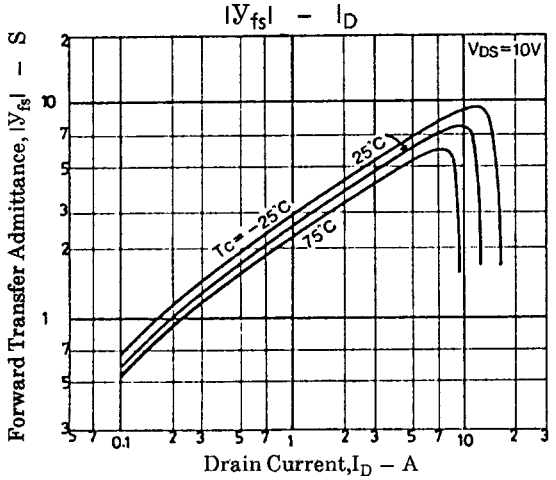


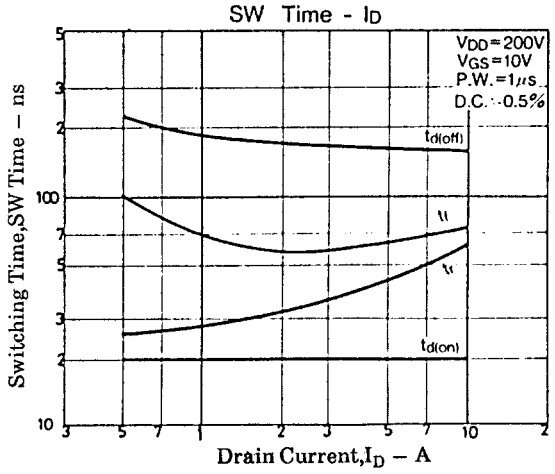


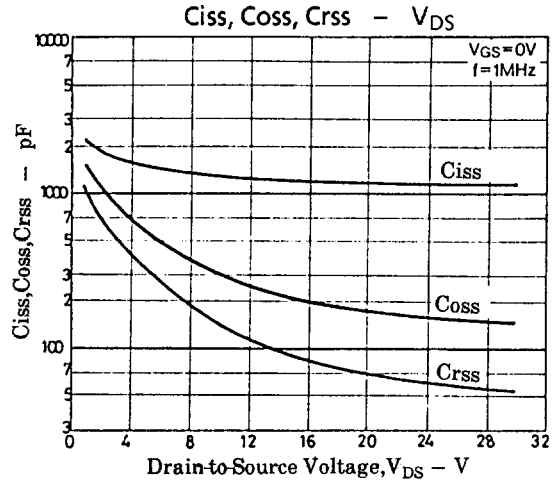


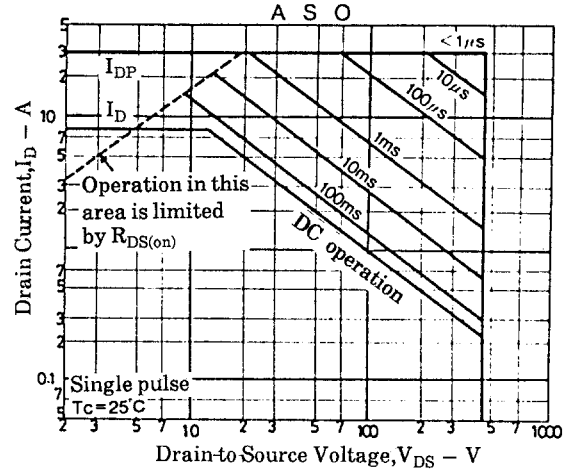

RDS(on) - VGS
Tc=25°C
ID=8A
4A
1A
Static Drain-to-Source ON-State Resistance, RDS(on) – Ω
Gate-to-Source Voltage, VGS – V

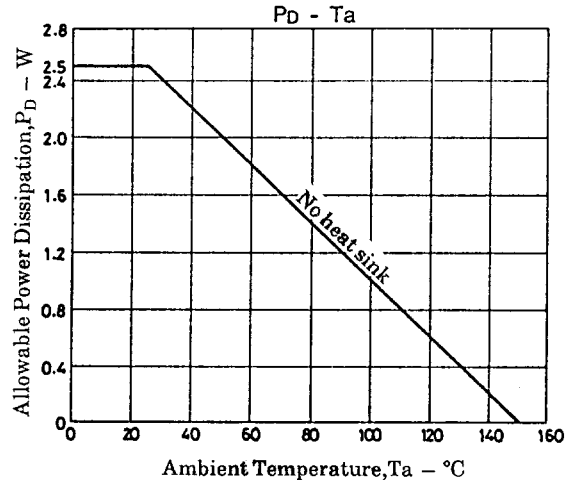

RDS(on) - Tc
ID=4A
VGS=10V
20V
Static Drain-to-Source ON-State Resistance, RDS(on) – Ω
Case Temperature, TC – °C

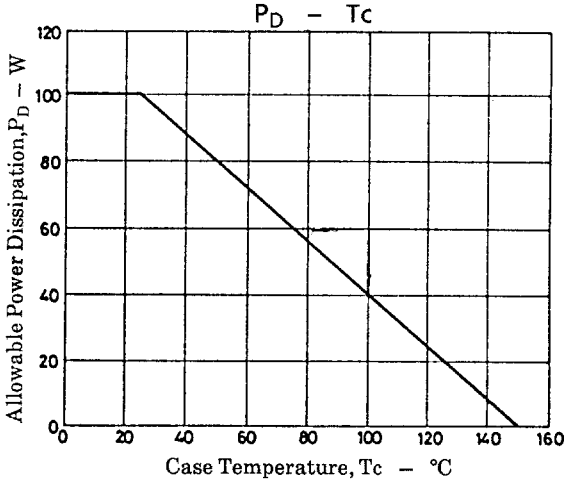

|Yfs| - ID
VDS=10V
25°C
Tc=–25°C
75°C
Forward Transfer Admittance, |Yfs| – S
Drain Current, ID – A


SW Time - ID
VDD=200V
VGS=10V
P.W.=1μs
D.C.≤0.5%
td(off)
tf
tr
td(on)
Switching Time, SW Time – ns
Drain Current, ID – A


Ciss, Coss, Crss - VDS
VGS=0V
f=1MHz
Ciss
Coss
Crss
Ciss, Coss, Crss – pF
Drain-to-Source Voltage, VDS – V


A S O
IDP
ID
Operation in this area is limited by RDS(on)
Single pulse
Tc=25°C
DC operation
1ms
10ms
100ms
Drain Current, ID – A
Drain-to-Source Voltage, VDS – V


PD - Ta
No heat sink
Allowable Power Dissipation, PD – W
Ambient Temperature, Ta – °C


PD – Tc
Allowable Power Dissipation, PD – W
Case Temperature, Tc – °C

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